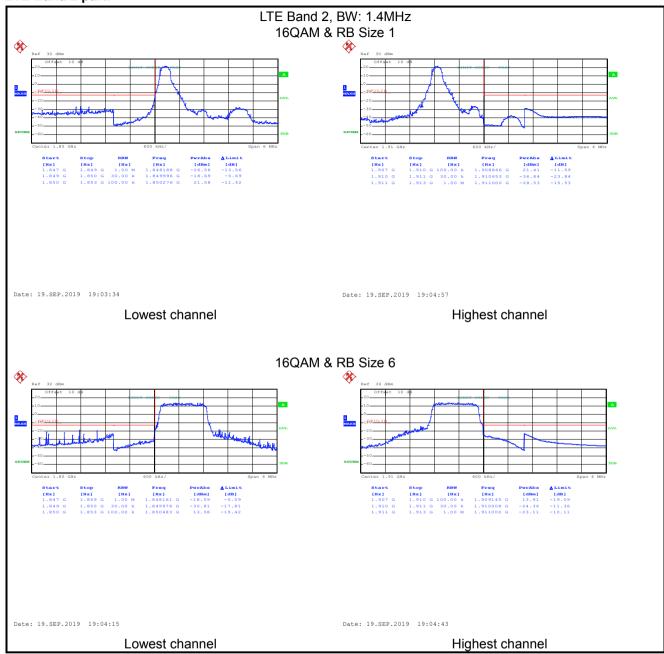


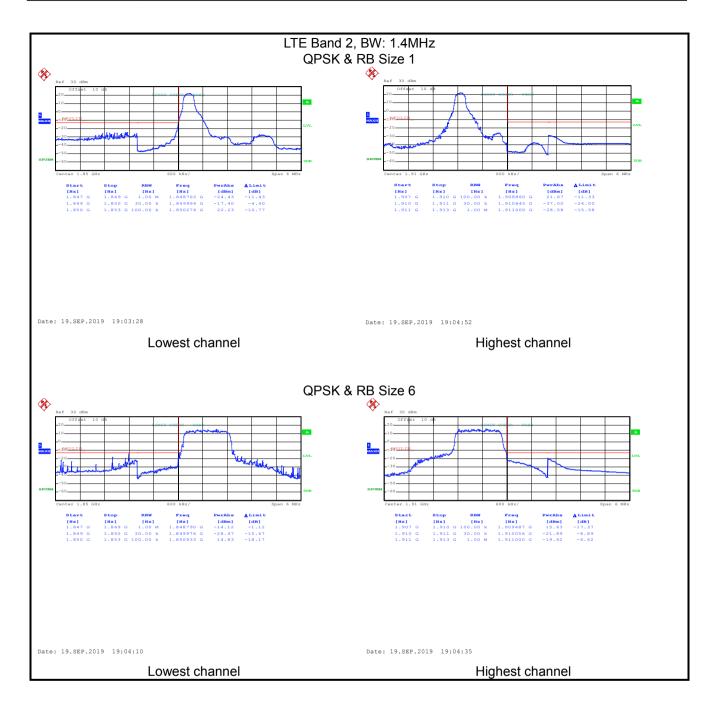


Band edge emission:

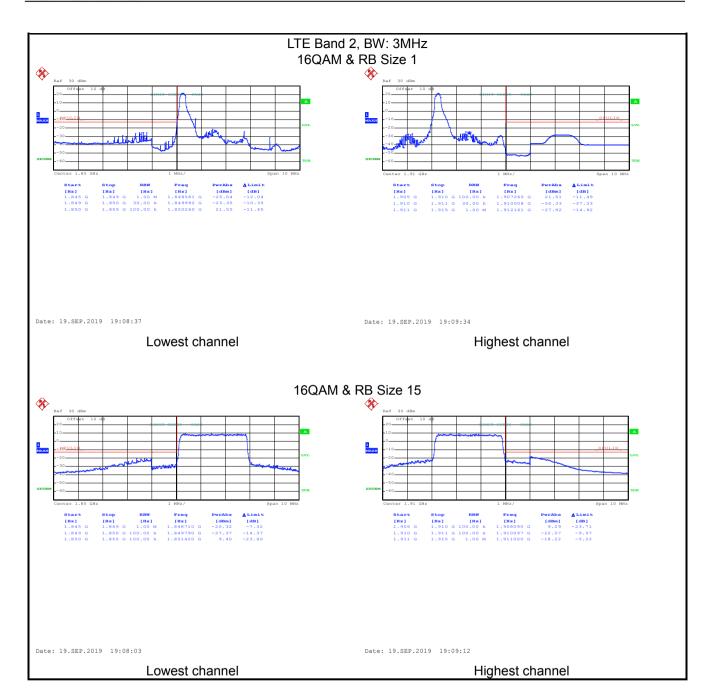
LTE Band 2 part:



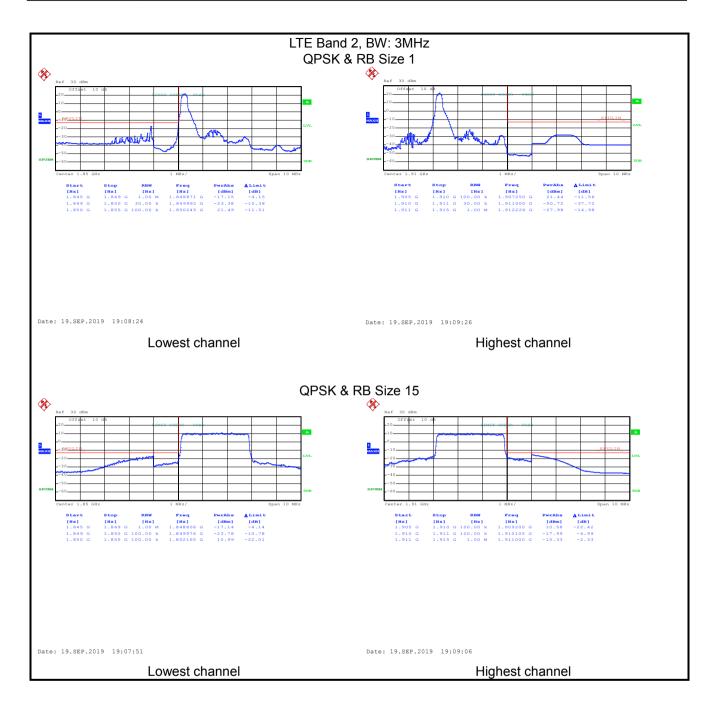




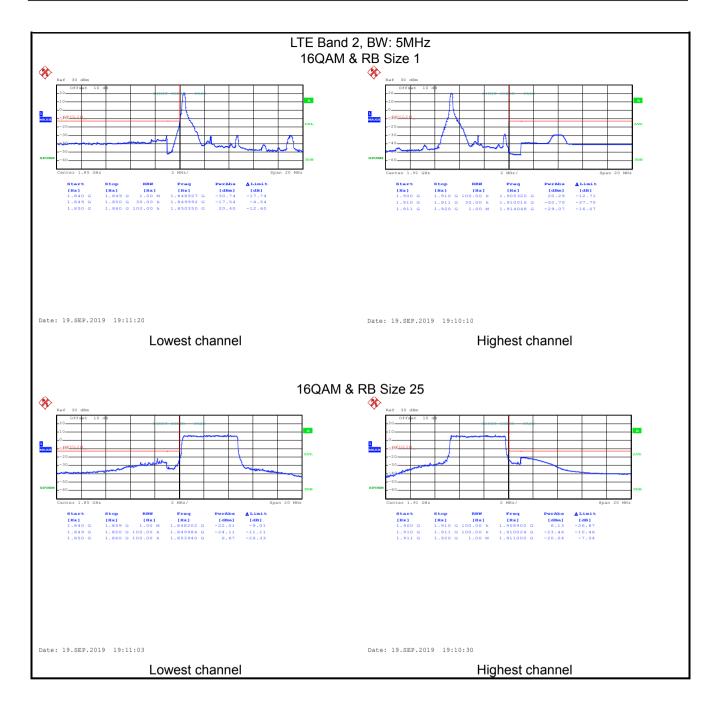




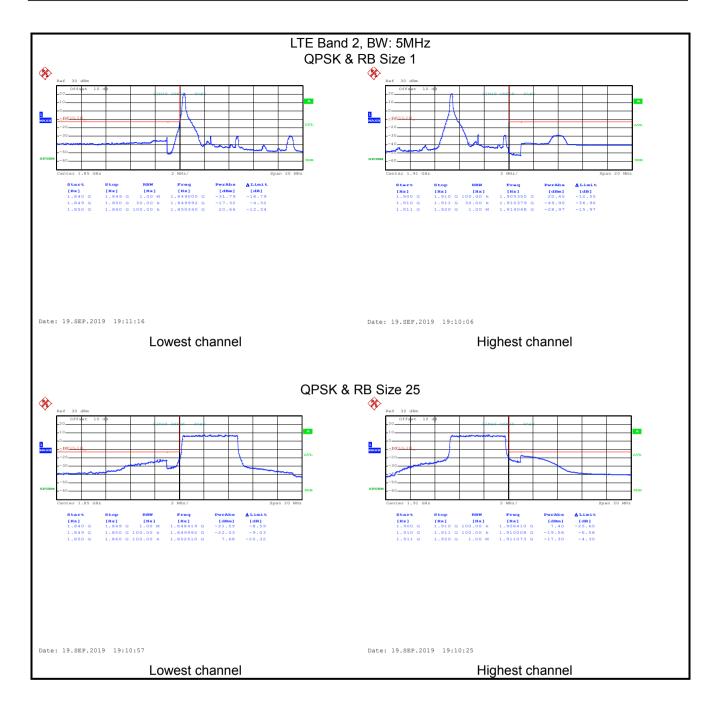




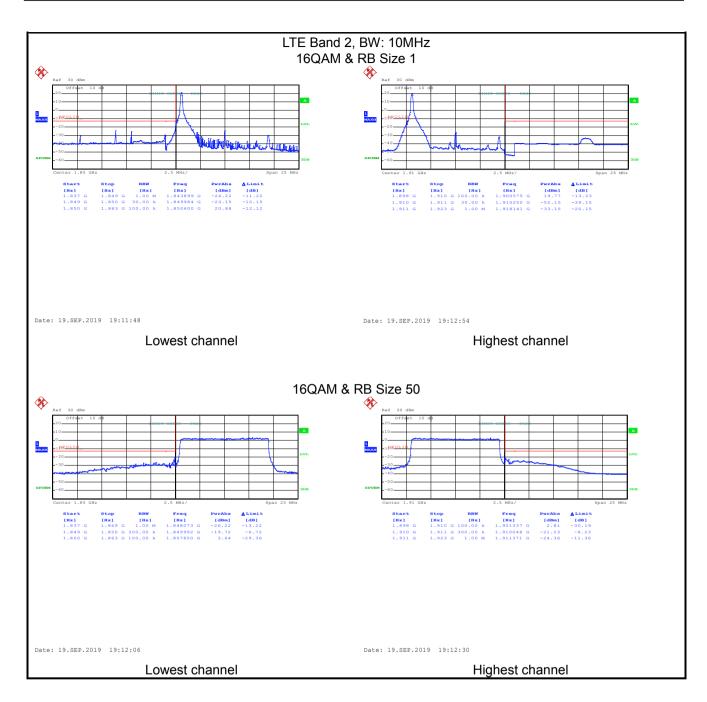




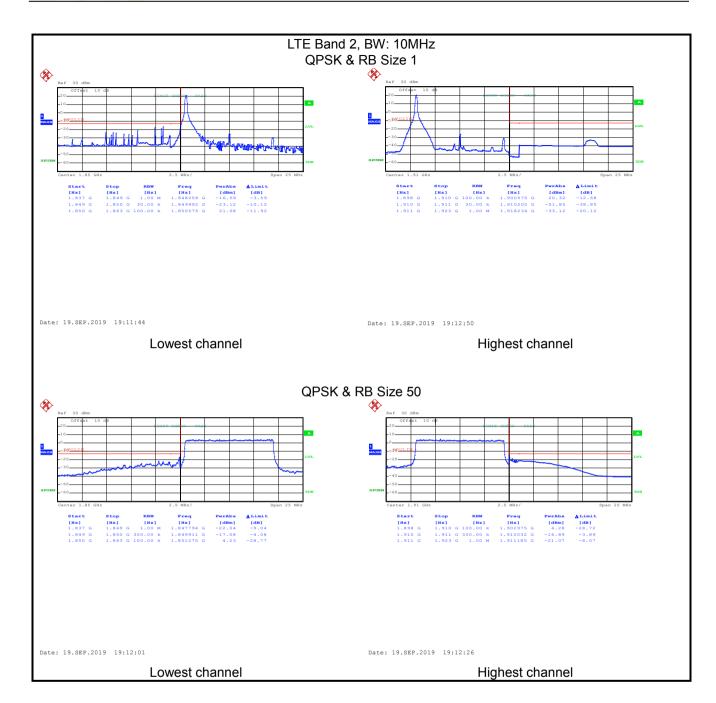




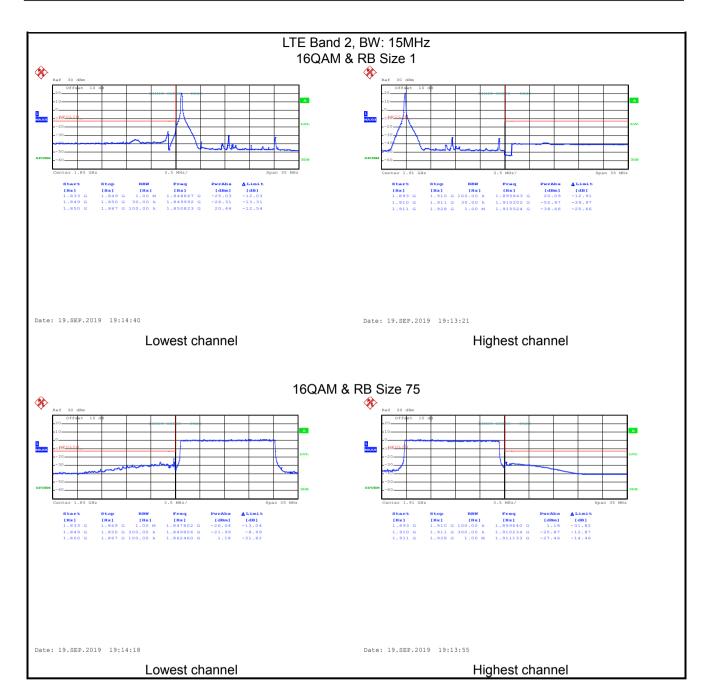




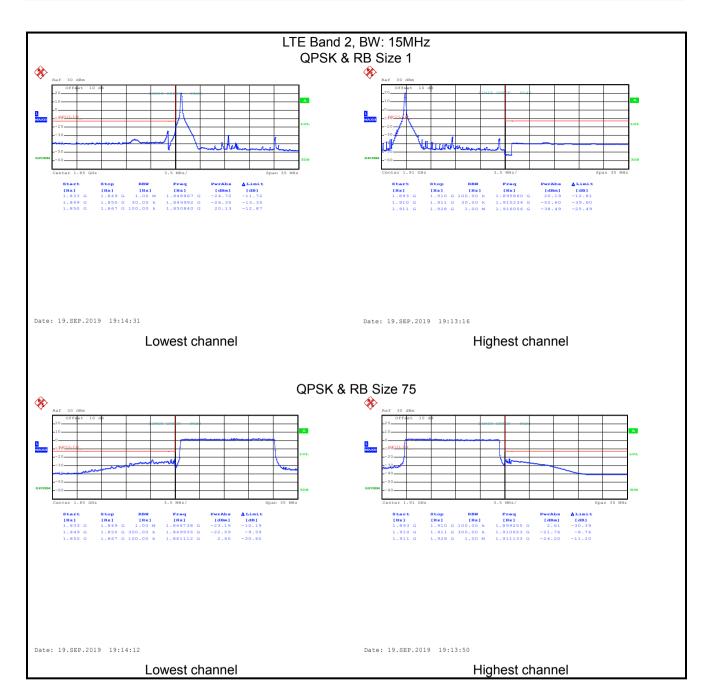




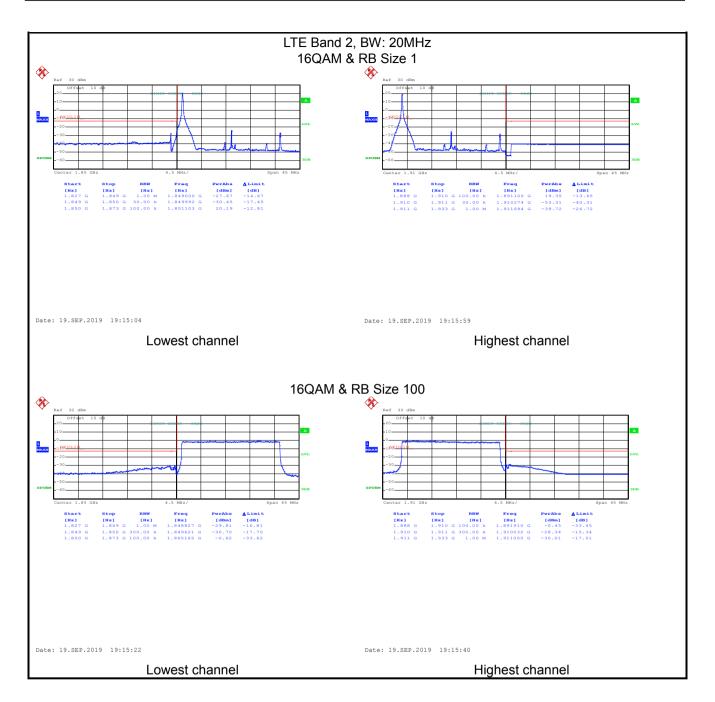




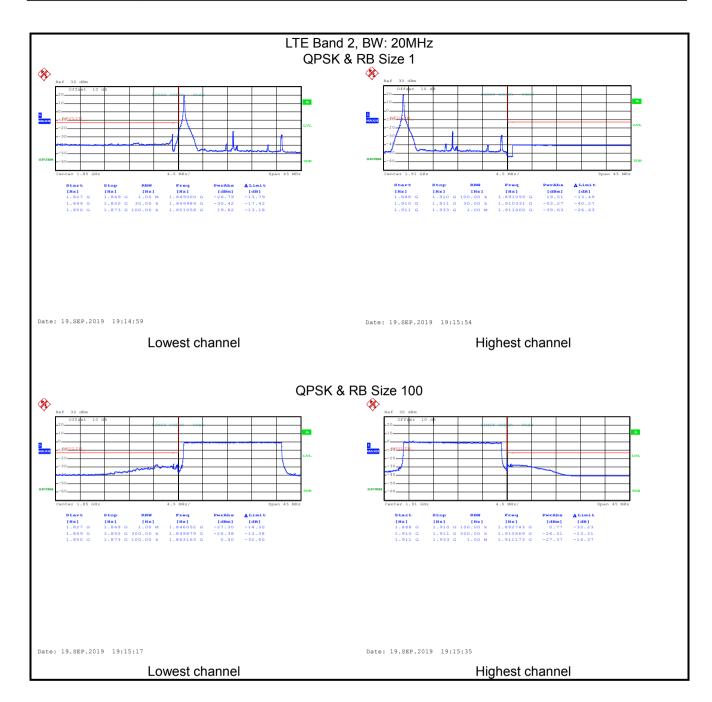






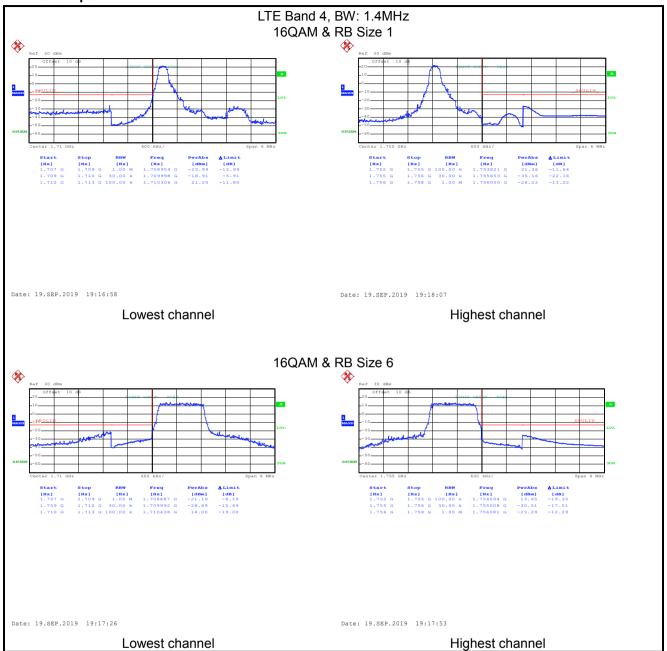




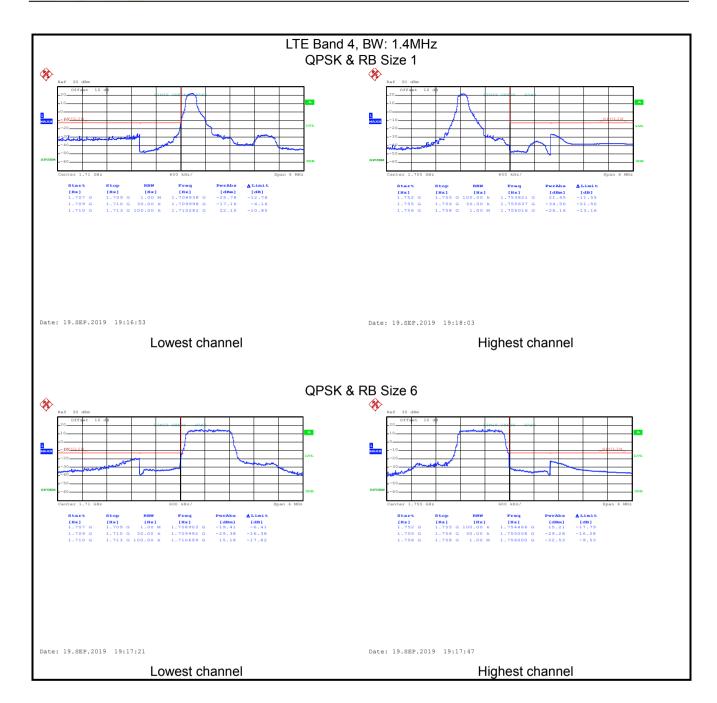




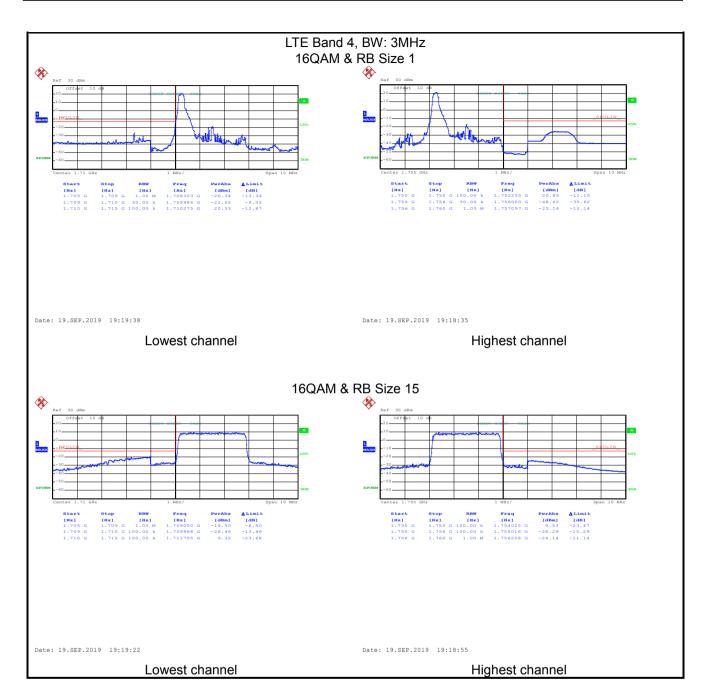
LTE Band 4 part:



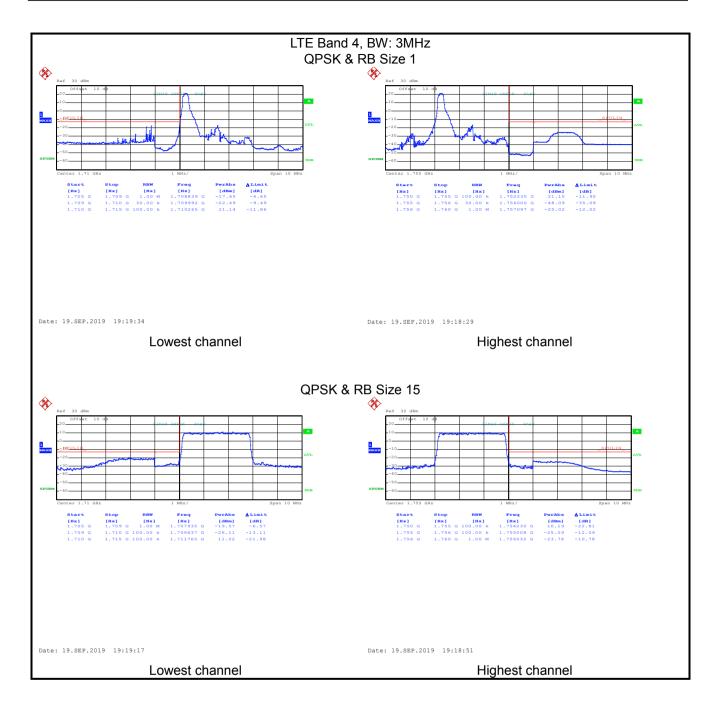




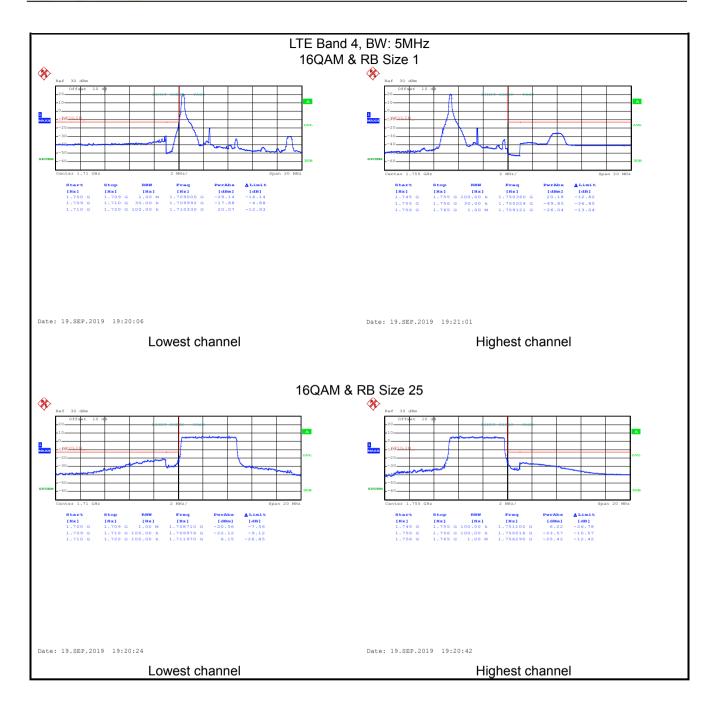




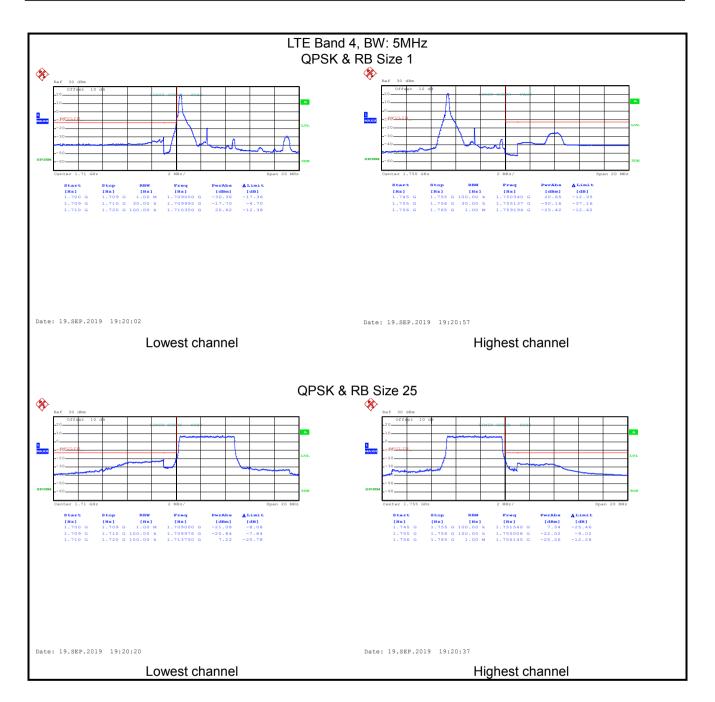




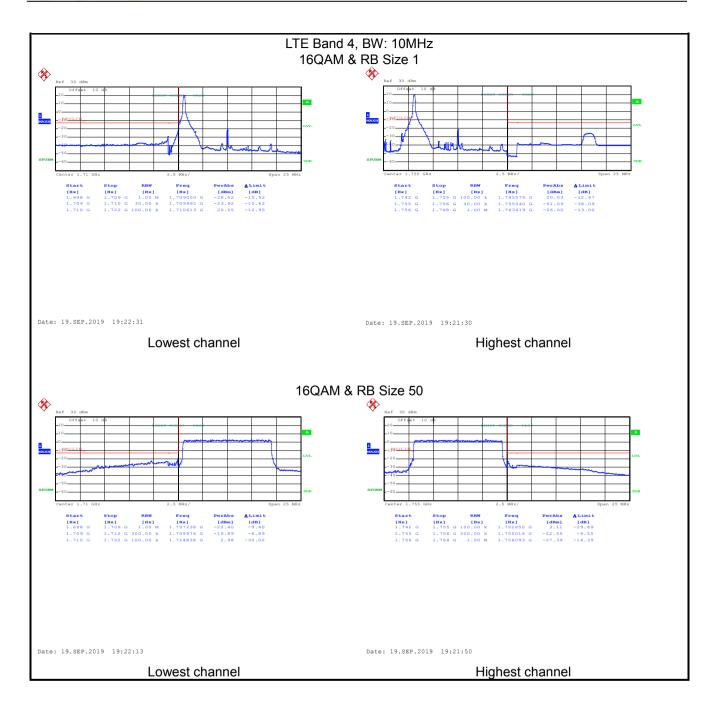




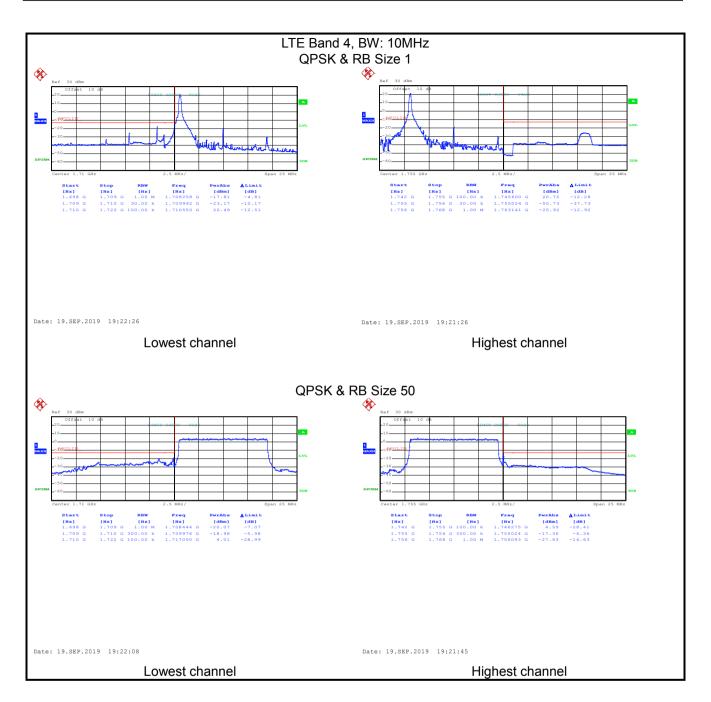




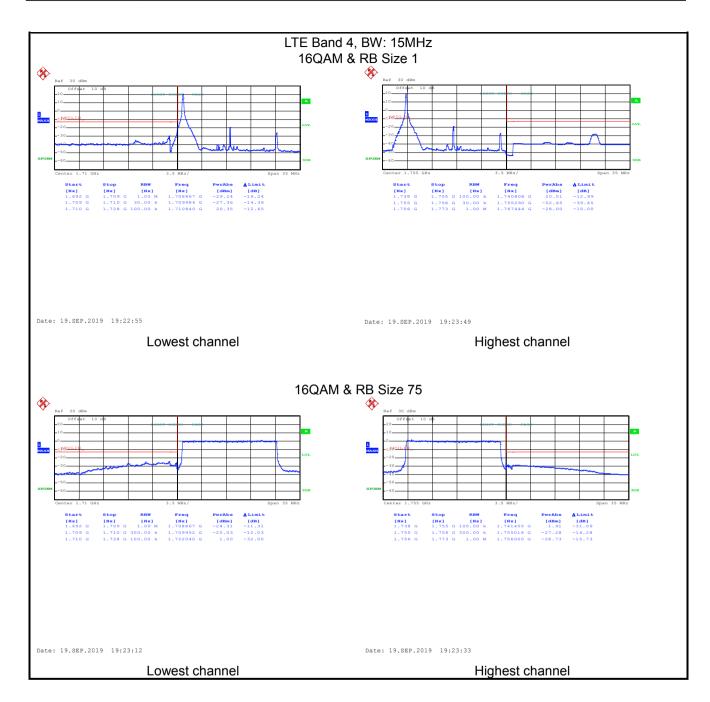




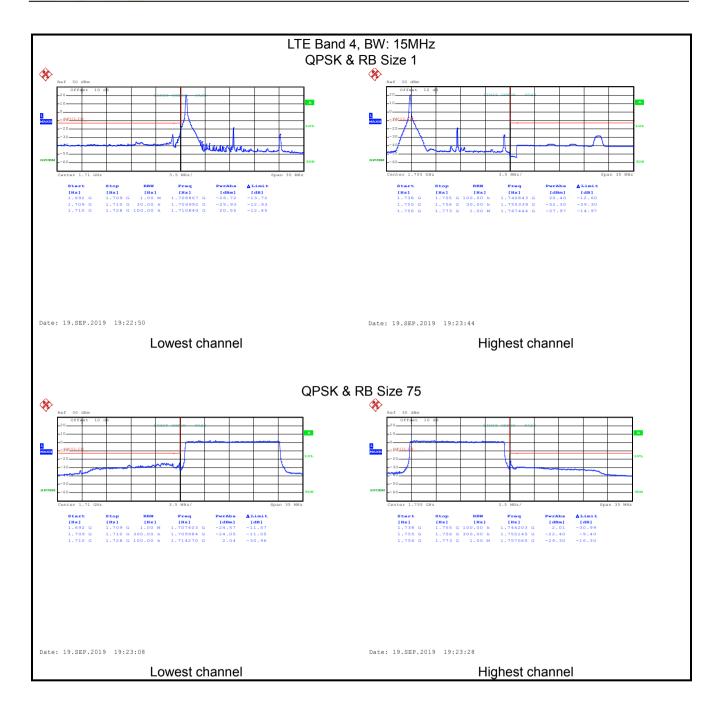




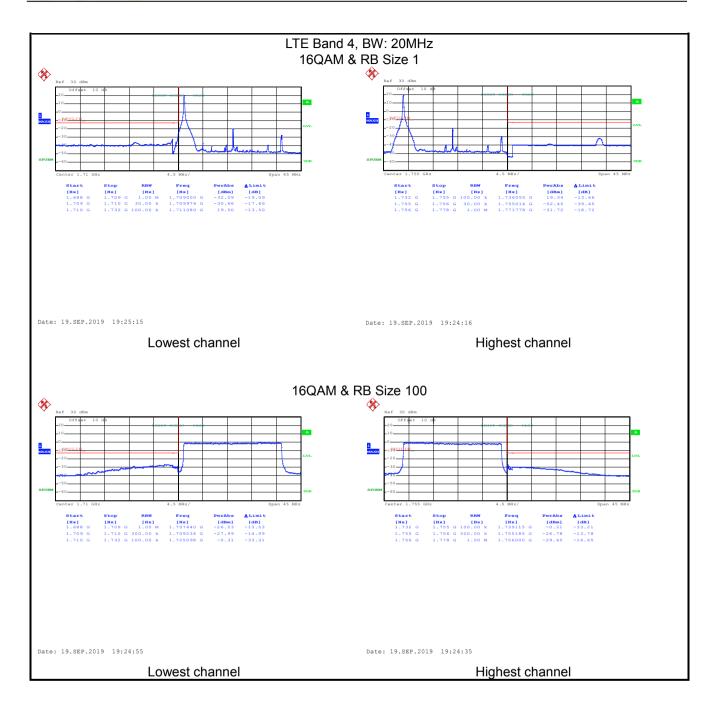




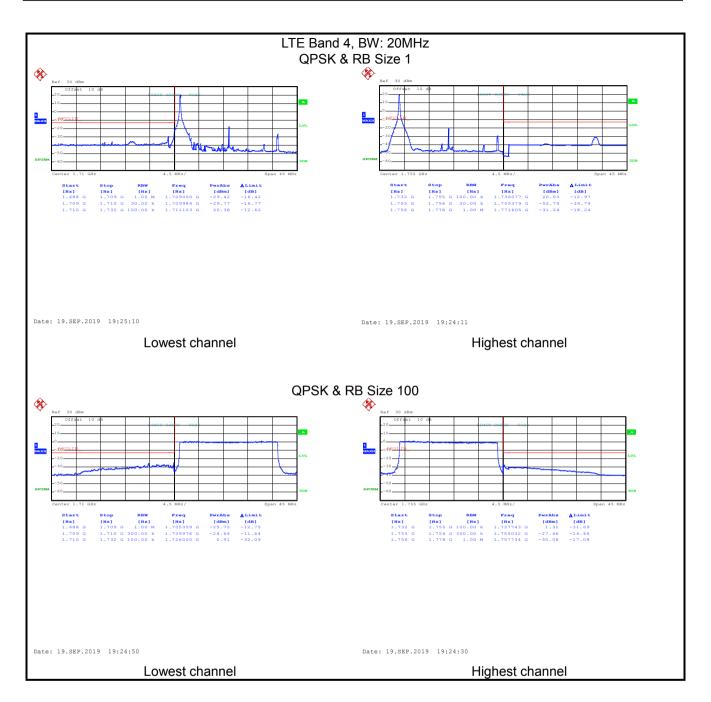














6.5 Field strength of spurious radiation measurement

0.5 Field Strellgtil of Spi	urious radiation measurement
Test Requirement:	Part 22.917(b), Part 24.238 (a), Part 27.53(g), Part 27.53(m), Part 27.53(h)
Limit:	LTE Band 2 & 4 & 5 & 12 & 17: The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log ₁₀ (P) dB (-13 dBm). LTE Band 7: For mobile digital stations, the attenuation factor shall be not less than 40 + 10 log (P) dB on all frequencies between the channel edge and 5 megahertz from the channel edge, 43 + 10 log (P) dB on all frequencies between 5 megahertz and X megahertz from the channel edge, and 55 + 10 log (P) dB on all frequencies more than X megahertz from the channel edge, where X is the greater of 6 megahertz or the actual emission bandwidth as defined in paragraph (m)(6) of this section. In addition, the attenuation factor shall not be less that 43 + 10 log (P) dB on all frequencies between 2490.5 MHz and 2496 MHz and 55 + 10 log (P) dB at or below 2490.5 MHz.
Test setup:	Below 1GHz
	Antenna Tower Ground Reference Plane Generator Amplifier Above 1GHz
	Artenna Tower Ground Reference Plane Test Receiver Test Receiver
Test Procedure:	 The EUT was placed on an non-conductive turntable using a non- conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	 During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations.
	The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels).



	Once spurious emission was identified, the power of the emission was determined using the substitution method.
	4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency.
	ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB)
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed

Measurement Data:

LTE Band 2 part:

	L	TE Band 2, WB: 1.4MF	łz		
	RB size 1 & RB offset 0				
Frequency (MHz)	Spurious Emission		Limit (dDm)	Result	
Frequency (Miriz)	Polarization	Level (dBm)	Limit (dBm)	Result	
		Lowest Channel			
3701.40	Vertical	-49.47			
5552.10	V	-42.79			
7402.00	V	-37.05	-13.00	Pass	
3701.40	Horizontal	-49.61	-13.00	Pass	
5552.10	Н	-42.73			
7402.00	Н	-38.11			
		Middle Channel			
3760.00	Vertical	-49.63		Pass	
5640.00	V	-43.12			
7520.00	V	-38.11	-13.00		
3760.00	Horizontal	-49.25	-13.00		
5640.00	Н	-42.66			
7520.00	Н	-38.79			
		Highest Channel			
3816.60	Vertical	-49.82	-13.00	Pass	
5724.90	V	-42.68			
7633.20	V	-38.05			
3816.60	Horizontal	-49.59			
5724.90	Н	-43.11			
7633.20	Н	-38.73			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 2, WB: 3MHz					
		RB size 1 & RB offset	0		
Frequency (MHz)	Spurious Emission		Limit (alDes)	Decult	
	Polarization	Level (dBm)	Limit (dBm)	Result	
	Lowest Channel				
3703.00	Vertical	-50.13		Pass	
5554.50	V	-42.11			
7406.00	V	-37.26	-13.00		
3703.00	Horizontal	-49.35	-13.00		
5554.50	Н	-42.28			
7406.00	Н	-37.80			
		Middle Channel			
3760.00	Vertical	-50.22		Pass	
5640.00	V	-41.86			
7520.00	V	-38.56	-13.00		
3760.00	Horizontal	-50.11	-13.00		
5640.00	Η	-41.85			
7520.00	Η	-37.66			
Highest Channel					
3817.00	Vertical	-50.13	-13.00 Pa		
5725.50	V	-42.30			
7634.00	V	-39.11		Pass	
3817.00	Horizontal	-50.86		Pass	
5725.50	Н	-42.23			
7634.00	H	-37.77			

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



		LTE Band 2, WB: 5MH	lz			
RB size 1 & RB offset 0						
Frequency (MHz)	Spurious Emission		Lineit (dDne)	Decult		
	Polarization	Level (dBm)	Limit (dBm)	Result		
Lowest Channel						
3705.00	Vertical	-49.20				
5557.50	V	-43.15		Pass		
7410.00	V	-38.42	-13.00			
3705.00	Horizontal	-49.23	-13.00	Pa55		
5557.50	Н	-43.10				
7410.00	Н	-38.41				
	Middle Channel					
3760.00	Vertical	-49.27		Pass		
5640.00	V	-42.89				
7520.00	V	-37.42	-13.00			
3760.00	Horizontal	-49.10	-13.00			
5640.00	Η	-41.55				
7520.00	Η	-37.03				
		Highest Channel				
3815.00	Vertical	-49.53				
5722.50	V	-41.97	-13.00			
7630.00	V	-38.40		Pass		
3815.00	Horizontal	-50.31		Pass		
5722.50	Н	-43.75				
7630.00	Н	-38.88				

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 2, WB: 10MHz				
RB size 1 & RB offset 0				
Frequency (MHz)	Spurious Emission		Limit (dDm)	Result
	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
3710.00	Vertical	-51.02		
5565.00	V	-42.78		
7420.00	V	-36.99	-13.00	Pass
3710.00	Horizontal	-48.24	-13.00	Fa55
5565.00	Н	-42.35		
7420.00	Н	-38.12		
		Middle Channel		
3760.00	Vertical	-51.60		
5640.00	V	-42.76		Pass
7520.00	V	-39.20	42.00	
3760.00	Horizontal	-50.77	-13.00	
5640.00	Н	-42.12		
7520.00	Н	-38.22		
		Highest Channel		
3810.00	Vertical	-50.82	-13.00	Pass
5715.00	V	-42.37		
7620.00	V	-40.12		
3810.00	Horizontal	-51.23		
5715.00	Н	-42.80		
7620.00	Н	-38.12		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 2, WB: 15MHz						
	RB size 1 & RB offset 0					
Frequency (MHz)	Spurious Emission		Limit (dDm)	Result		
	Polarization	Level (dBm)	Limit (dBm)	Result		
	Lowest Channel					
3715.00	Vertical	-49.61				
5572.50	V	-43.86				
7430.00	V	-39.04	-13.00	Pass		
3715.00	Horizontal	-48.99	-13.00	F455		
5572.50	Н	-43.76				
7430.00	Н	-39.10				
		Middle Channel				
3760.00	Vertical	-49.78		Pass		
5640.00	V	-42.56				
7520.00	V	-38.14	-13.00			
3760.00	Horizontal	-50.34	-13.00			
5640.00	Н	-41.58				
7520.00	Н	-38.34				
	Highest Channel					
3805.00	Vertical	-50.34	-13.00			
5707.50	V	-42.13				
7610.00	V	-38.30		Desc		
3805.00	Horizontal	-50.44		Pass		
5707.50	Н	-42.57				
7610.00	Н	-38.91				

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LTE Band 2, WB: 20MHz					
RB size 1 & RB offset 0						
Fraguenay (MHz)	Spurious Emission		Limit (dDm)	Dogult		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result		
Lowest Channel						
3720.00	Vertical	-50.13				
5580.00	V	-42.29				
7440.00	V	-36.25	-13.00	Pass		
3720.00	Horizontal	-48.51	-13.00	rass		
5580.00	Н	-43.38				
7440.00	Н	-39.16				
Middle Channel						
3760.00	Vertical	-52.13				
5640.00	V	-43.81				
7520.00	V	-40.15	-13.00	Pass		
3760.00	Horizontal	-51.43	-13.00	rass		
5640.00	Η	-42.87				
7520.00	Н	-39.08				
		Highest Channel				
3800.00	Vertical	-51.23				
5700.00	V	-43.22				
7600.00	V	-41.25	-13.00	Pass		
3800.00	Horizontal	-51.90	-13.00	Pass		
5700.00	Н	-43.12				
7600.00	Н	-39.53				

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 4 part:

LTE Band 4, WB: 1.4MHz					
		RB size 1 & RB offset (0		
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result	
Frequency (MITIZ)	Polarization	Level (dBm)	Limit (dbiii)	Kesuit	
		Lowest Channel			
3421.40	Vertical	-45.34			
5132.10	V	-44.73			
6842.80	V	-38.52	-13.00	Pass	
3421.40	Horizontal	-43.51	-13.00	Pa55	
5132.10	Н	-44.46			
6842.80	Н	-38.48			
Middle Channel					
3465.00	Vertical	-46.37			
5197.50	V	-48.16			
6930.00	V	-39.88	12.00	Pass	
3465.00	Horizontal	-44.09	-13.00	Pass	
5197.50	Н	-45.34			
6930.00	Н	-38.99			
		Highest Channel			
3508.60	Vertical	-47.41			
5262.90	V	-49.35			
7017.20	V	-40.22	12.00	Door	
3508.60	Horizontal	-45.30	-13.00	Pass	
5262.90	Н	-46.21			
7017.20	Н	-39.16			

Note:

The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report. For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 4, WB: 3MHz							
	1	RB size 1 & RB offset 0					
Eroguenov (MHz)	Spurious	s Emission	Limit (dDm)	Result			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result			
		Lowest Channel					
3423.00	Vertical	-47.38					
5134.50	V	-49.25					
6846.00	V	-39.12	-13.00	Pass			
3423.00	Horizontal	-45.69	-13.00	Pass			
5134.50	Н	-46.87					
6846.00	Н	-39.20					
	Middle Channel						
3465.00	Vertical	-48.16					
5197.50	V	-50.22					
6930.00	V	-39.69	42.00	Dese			
3465.00	Horizontal	-46.13	-13.00	Pass			
5197.50	Н	-47.24					
6930.00	Н	-39.46					
		Highest Channel					
3507.00	Vertical	-48.32					
5260.50	V	-49.97					
7014.00	V	-40.03	42.00	Dana			
3507.00	Horizontal	-46.79	-13.00	Pass			
5260.50	Н	-48.35					
7014.00	Н	-39.88					

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 4, WB: 5MHz					
		RB size 1 & RB offset	0		
Eroguanay (MUz)	Spurious Emission		Limit (dPm)	Decult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3425.00	Vertical	-46.29			
5137.50	V	-44.98			
6850.00	V	-38.26	-13.00	Pass	
3425.00	Horizontal	-43.36	-13.00	Fa55	
5137.50	Н	-45.10			
6850.00	Н	-39.05			
Middle Channel					
3465.00	Vertical	-46.91			
5197.50	V	-49.02			
6930.00	V	-40.22	-13.00	Pass	
3465.00	Horizontal	-45.18	-13.00	Fa55	
5197.50	Н	-46.31			
6930.00	Н	-39.55			
		Highest Channel			
3505.00	Vertical	-48.42			
5257.50	V	-49.56			
7010.00	V	-41.06	-13.00	Pass	
3505.00	Horizontal	-45.88	-13.00	Pass	
5257.50	Н	-46.90			
7010.00	Н	-39.85			

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 4, WB: 10MHz					
		RB size 1 & RB offset (0		
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result	
Frequency (IVIF12)	Polarization	Level (dBm)	Lilliit (ubili)	Result	
		Lowest Channel			
3430.00	Vertical	-48.24			
5145.00	V	-49.64			
6860.00	V	-39.55	-13.00	Pass	
3430.00	Horizontal	-46.12	-13.00	Fd55	
5145.00	Н	-47.30			
6860.00	Н	-39.88			
Middle Channel					
3465.00	Vertical	-48.67			
5197.50	V	-50.62			
6930.00	V	-39.11	-13.00	Pass	
3465.00	Horizontal	-45.81	-13.00	Fd55	
5197.50	Н	-47.96			
6930.00	Н	-39.20			
		Highest Channel			
3500.00	Vertical	-47.92			
5250.00	V	-49.65			
7000.00	V	-40.10	42.00	Door	
3500.00	Horizontal	-46.21	-13.00	Pass	
5250.00	Н	-48.16			
7000.00	Н	-39.15			

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 4, WB: 15MHz						
RB size 1 & RB offset 0						
Fragues av (MHz)	Spurious Emission		Limit (dDm)	Decult		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result		
3435.00	Vertical	-46.68				
5152.50	V	-44.61				
6870.00	V	-39.12	-13.00	Pass		
3435.00	Horizontal	-44.16	-13.00	F455		
5152.50	Н	-46.58				
6870.00	Н	-39.11				
Middle Channel						
3465.00	Vertical	-46.84				
5197.50	V	-49.68				
6930.00	V	-39.55	-13.00	Pass		
3465.00	Horizontal	-44.73	-13.00	F455		
5197.50	Н	-46.91				
6930.00	Н	-39.79				
		Highest Channel				
3495.00	Vertical	-49.20				
5242.50	V	-49.67				
6990.00	V	-41.52	-13.00	Pass		
3495.00	Horizontal	-46.12	-13.00	Pass		
5242.50	Н	-47.14				
6990.00	Н	-40.22				

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 4, WB: 20MHz					
		RB size 1 & RB offset (0		
Erogueney (MHz)	Spurious Emission		Limit (dRm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
		Lowest Channel			
3440.00	Vertical	-47.86			
5160.00	V	-48.52			
6880.00	V	-38.88	-13.00	Pass	
3440.00	Horizontal	-45.26	-13.00	Fd55	
5160.00	Н	-47.94			
6880.00	Н	-38.99			
Middle Channel					
3465.00	Vertical	-48.79			
5197.50	V	-50.26			
6930.00	V	-39.05	-13.00	Pass	
3465.00	Horizontal	-46.32	-13.00	Fd55	
5197.50	Н	-47.55			
6930.00	Н	-39.26			
		Highest Channel			
3490.00	Vertical	-48.34			
5235.00	V	-49.98			
6980.00	V	-39.54	-13.00	Door	
3490.00	Horizontal	-46.57	-13.00	Pass	
5235.00	Н	-47.89			
6980.00	Н	-38.76			

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



6.6 Frequency stability V.S. Temperature measurement

Test Requirement:	Part 22.355, Part 24.235, Part 27.54, Part 2.1055(a)(1)(b)
Limit:	±2.5ppm
Test setup:	SS Divider Temperature & Humidity Chamber Power Source
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (worst case):

LTE Band 2 part:

	requency: LTE Band 2			channel=1880.0	OMHZ
Power supplied (Vdc)	Temperature (°C)	Hz	ency error ppm	Limit (ppm)	Result
(100)		QPSK	ppiii		
	-30	194	0.103191		
	-20	155	0.082447		
	-10	163	0.086702		
	0	123	0.065426]	
3.80	10	188	0.100000	±2.5	Pass
	20	130	0.069149		
	30	114	0.060638		
	40	105	0.055851		
	50	151	0.080319		
		16QAM			
	-30	165	0.087766		
	-20	150	0.079787		
	-10	123	0.065426		
	0	122	0.064894		
3.80	10	144	0.076596	±2.5	Pass
	20	140	0.074468		
	30	156	0.082979	1	
	40	137	0.072872		
	50	133	0.070745]	





LTE Band 4 part:

Reference Fr	equency: LTE Band 4	(10MHz) Midd	le channel=20175	channel=1732.5	0MHz
Power supplied	Temperature (°C)	Freque	ency error	Limit (ppm)	Result
(Vdc)	remperature (C)	Hz	ppm	Limit (ppin)	Result
		QPSK			
	-30	196	0.113131		
	-20	155	0.089466		
	-10	163	0.094084		
	0	123	0.070996		
3.80	10	185	0.106782	±2.5	Pass
	20	174	0.100433		
	30	114	0.065801		
	40	105	0.060606		
	50	157	0.090620		
		16QAM			
	-30	166	0.095815		
	-20	150	0.086580		
	-10	127	0.073304		
	0	121	0.069841		
3.80	10	144	0.083117	±2.5	Pass
	20	145	0.083694		
	30	156	0.090043]	
	40	133	0.076768		
	50	131	0.075613		



6.7 Frequency stability V.S. Voltage measurement

Test Requirement:	Part 22.355, Part 24.235, Part 27.54, Part 2.1055(d)(2)
Limit:	±2.5ppm
Test setup:	SS EUT Divider Temperature & Humidity Chamber Power Source
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 5.10 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed



Measurement Data (worst case):

LTE Band 2 part:

Reference Frequency: LTE Band 2(10MHz) Middle channel=18900 channel=1880.00MHz					
Temperature (°C)	Power supplied	Frequen	cy error	Limit (ppm)	Result
Temperature (C)	(Vdc)	Hz	ppm	Еши (ррш)	Kesuit
		QPSK			
	4.35	96	0.051064	±2.5	
25	3.80	74	0.039362		Pass
	3.50	86	0.045745		
		16QAM			
	4.35	83	0.044149		
25	3.80	60	0.031915	±2.5	Pass
	3.50	74	0.039362		
Note: Only the worst car	se shown in the report.				

LTE Band 4 part:

Reference Fr	equency: LTE Band	4(10MHz) Middle	channel=20175	channel=1732.5	0MHz
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Popult
	(Vdc)	Hz	ppm	Limit (ppm)	Result
		QPSK			
25	4.35	96	0.055411	±2.5	Pass
	3.80	80	0.046176		
	3.50	74	0.042713		
		16QAM			
25	4.35	78	0.045022	±2.5	Pass
	3.80	80	0.046176		
	3.50	90	0.051948		